



SANYO Semiconductors

# DATA SHEET

An ON Semiconductor Company

## 2SB1201/2SD1801 — PNP/NPN Epitaxial Planar Silicon Transistor

### High-Current Switching Applications

#### Applications

- Voltage regulators, relay drivers, lamp drivers, electrical equipment

#### Features

- Adoption of FBET, MBIT processes
- Low collector-to-emitter saturation voltage
- Small and slim package making it easy to make 2SB1201/2SD1801-used sets smaller
- Large current capacitance and wide ASO
- Fast switching speed

#### Specifications ( ) : 2SB1201

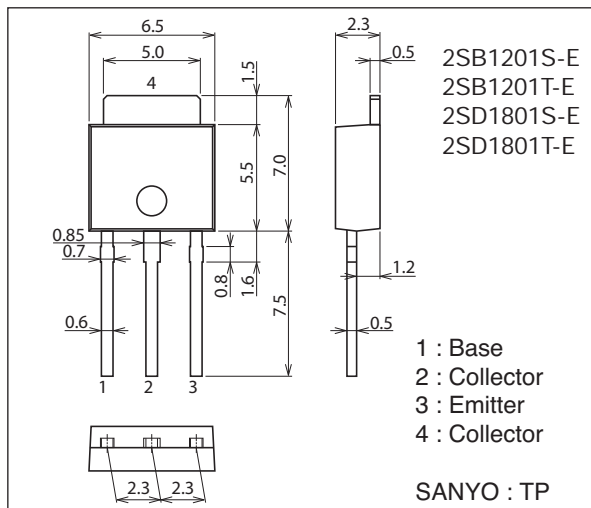
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CB0</sub>		(-)60	V
Collector-to-Emitter Voltage	V <sub>CE0</sub>		(-)50	V
Emitter-to-Base Voltage	V <sub>EB0</sub>		(-)6	V
Collector Current	I <sub>C</sub>		(-)2	A
Collector Current (Pulse)	I <sub>CP</sub>		(-)4	A

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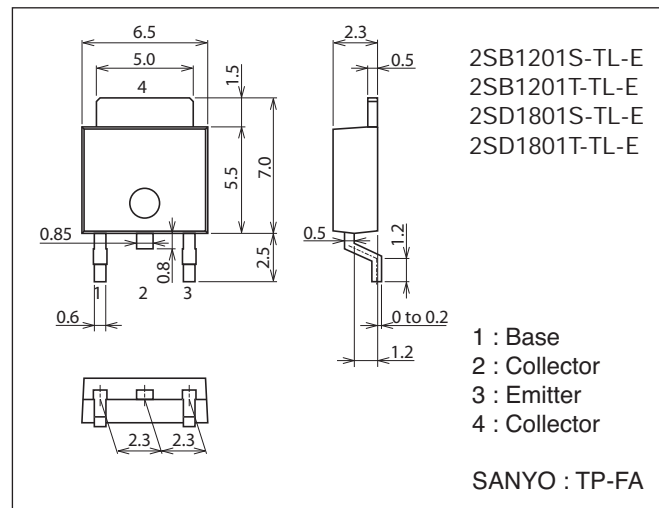
#### Package Dimensions unit : mm (typ)

7518-003



#### Package Dimensions unit : mm (typ)

7003-003

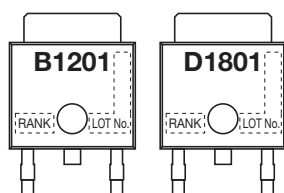


#### Product & Package Information

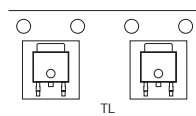
- Package : TP
- JEITA, JEDEC : SC-64, TO-251
- Minimum Packing Quantity : 500 pcs./bag

- Package : TP-FA
- JEITA, JEDEC : SC-63, TO-252
- Minimum Packing Quantity : 700 pcs./reel

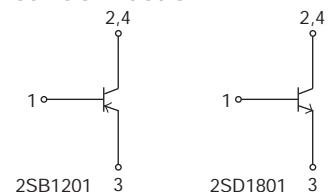
#### Marking (TP, TP-FA)



#### Packing Type (TP-FA) : TL



#### Electrical Connection



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<http://semicon.sanyo.com/en/network>

## 2SB1201/2SD1801

Continued from preceding page.

Parameter	Symbol	Conditions	Ratings	Unit
Collector Dissipation	P <sub>C</sub>		0.8	W
		T <sub>C</sub> =25°C	15	W
Junction Temperature	T <sub>J</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

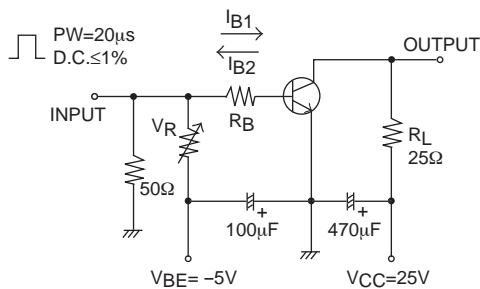
### Electrical Characteristics at T<sub>a</sub>=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)50V, I <sub>E</sub> =0A			(-)100	nA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0A			(-)100	nA
DC Current Gain	h <sub>FE1</sub>	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)100mA	100*		560*	
	h <sub>FE2</sub>	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)1.5A	40			
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)50mA		150		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)10V, f=1MHz		(22)12		pF
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =(-)1A, I <sub>B</sub> =(-)50mA		(-0.3)0.15	(-0.7)0.4	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	V <sub>CE</sub> =(-)1A, I <sub>C</sub> =(-)50mA		(-)0.9	(-)1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =(-)10μA, I <sub>E</sub> =0A	(-)60			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =(-)1mA, R <sub>BE</sub> =∞	(-)50			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =(-)10μA, I <sub>C</sub> =0A	(-)6			V
Turn-On Time	t <sub>on</sub>	See specified Test Circuit.		60		ns
Storage Time	t <sub>stg</sub>			(450)550		ns
Fall Time	t <sub>f</sub>			30		ns

\* : The 2SB1201/2SD1801 are classified by 100mA h<sub>FE</sub> as follows :

Rank	R	S	T	U
h <sub>FE</sub>	100 to 200	140 to 280	200 to 400	280 to 560

### Switching Time Test Circuit

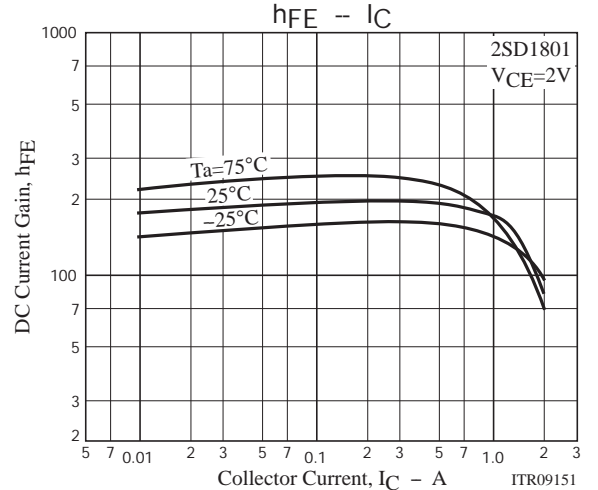
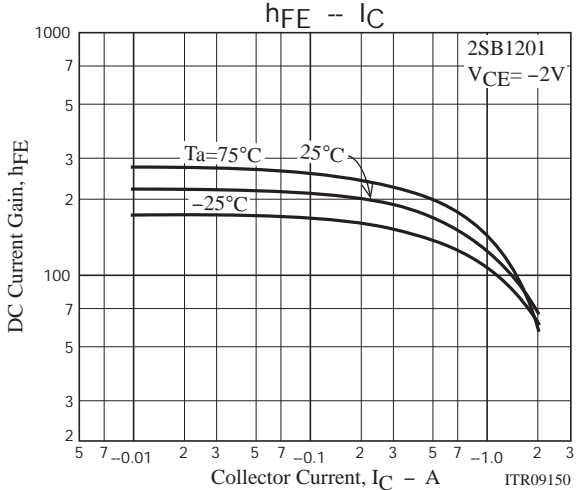
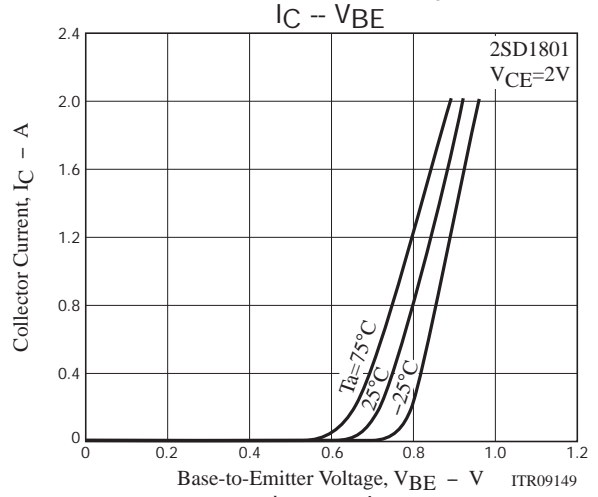
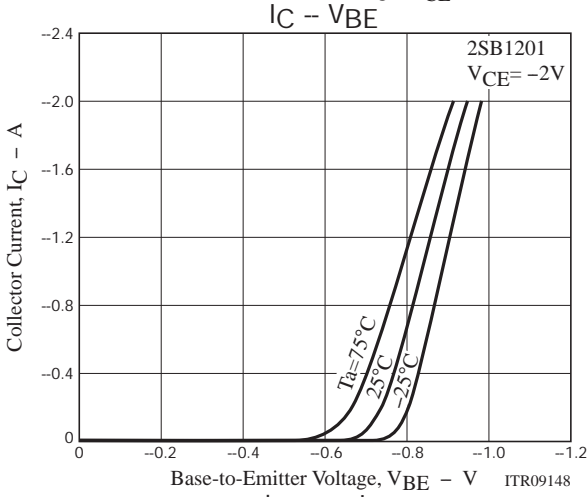
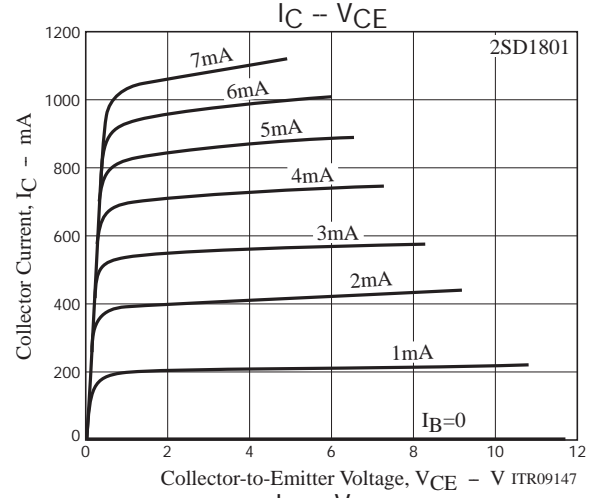
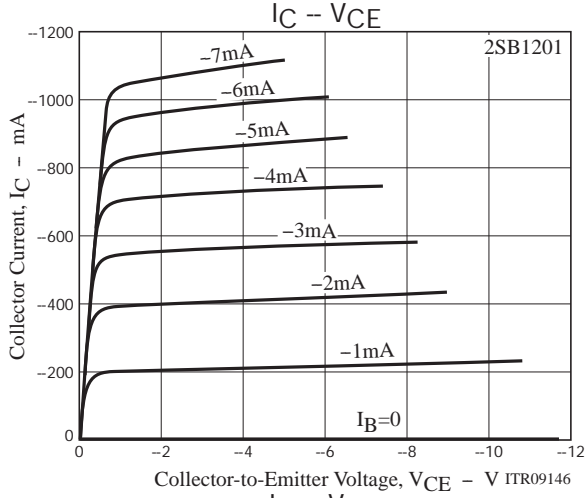
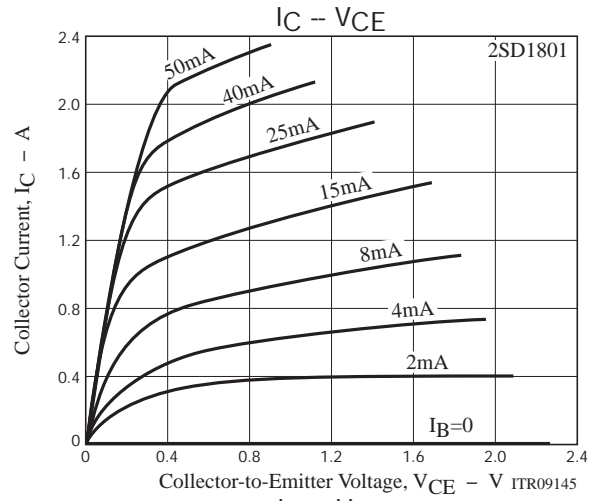
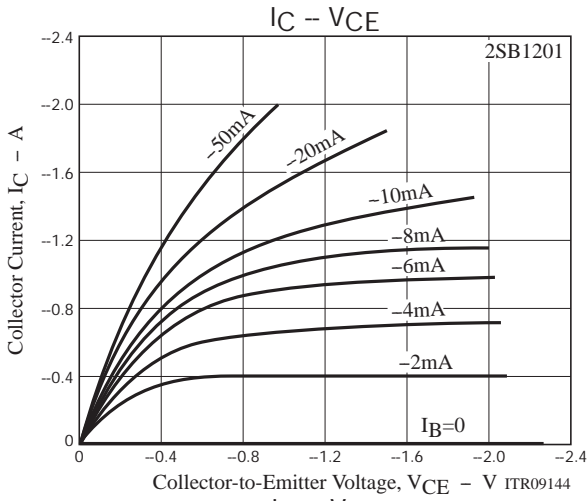


I<sub>C</sub>=10I<sub>B1</sub>= -10I<sub>B2</sub>=500mA, V<sub>CC</sub>=25V  
 For PNP, the polarity is reversed.

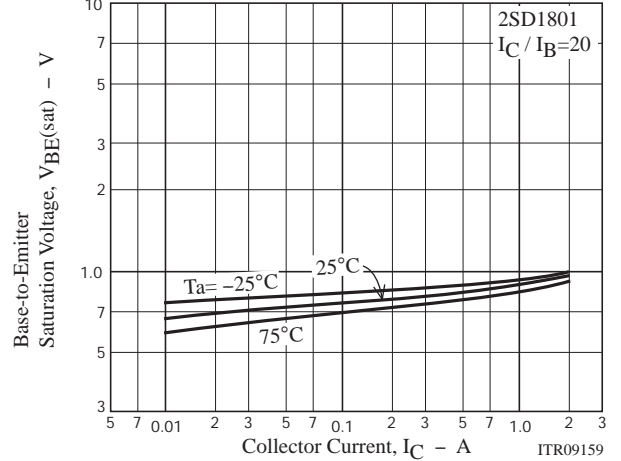
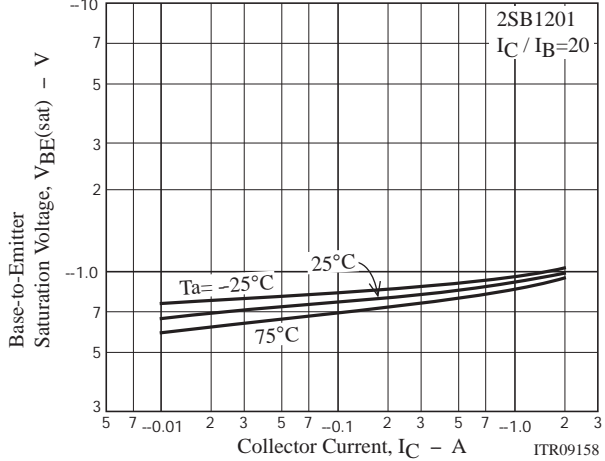
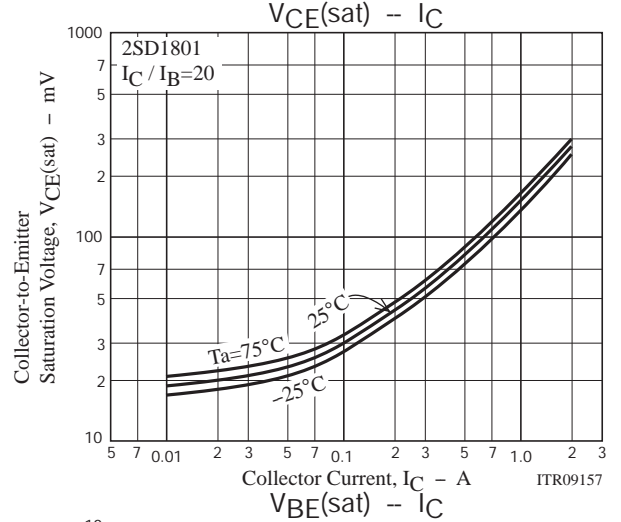
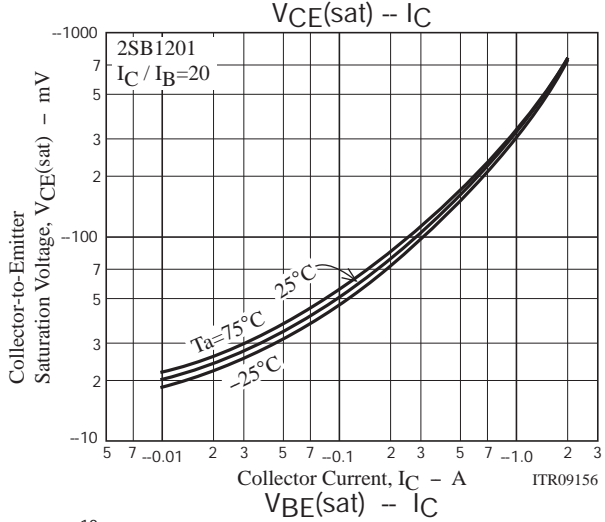
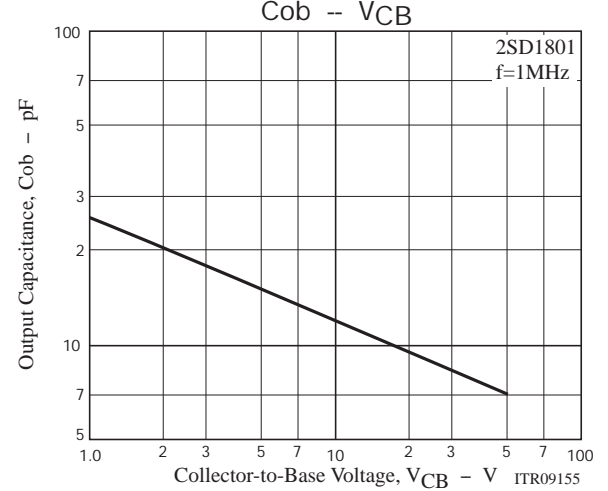
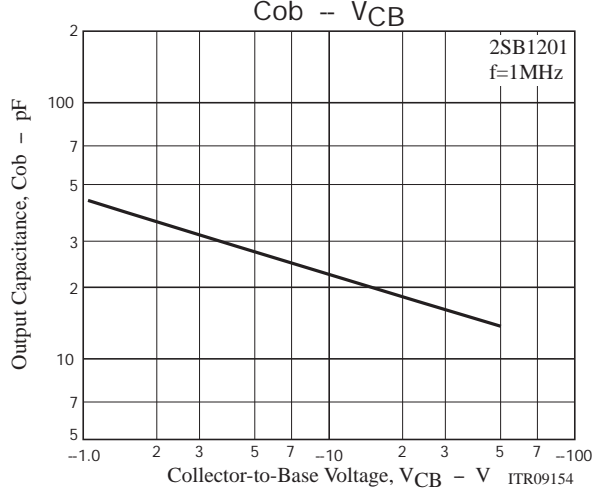
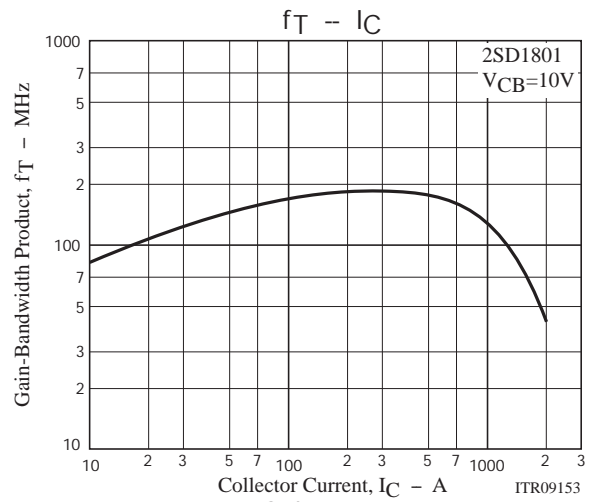
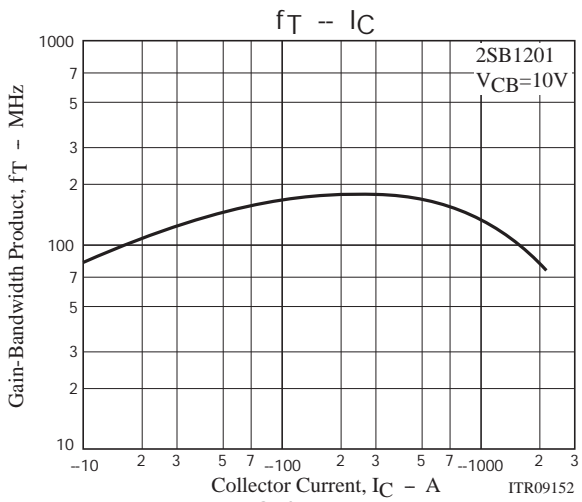
### Ordering Information

Device	Package	Shipping	memo
2SB1201S-E	TP	500pcs./bag	Pb Free
2SB1201T-E	TP	500pcs./bag	
2SD1801S-E	TP	500pcs./bag	
2SD1801T-E	TP	500pcs./bag	
2SB1201S-TL-E	TP-FA	700pcs./reel	
2SB1201T-TL-E	TP-FA	700pcs./reel	
2SD1801S-TL-E	TP-FA	700pcs./reel	
2SD1801T-TL-E	TP-FA	700pcs./reel	

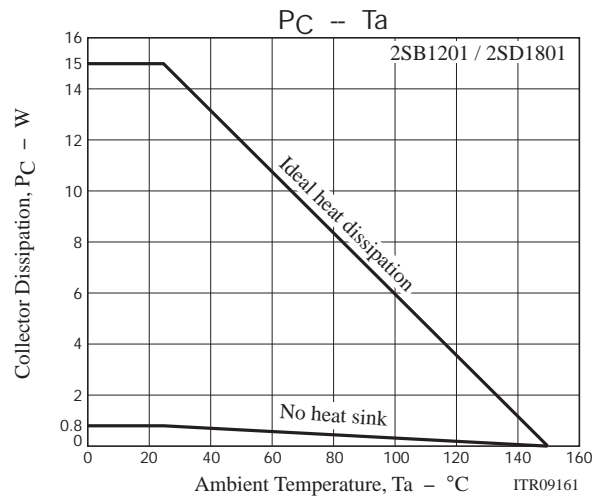
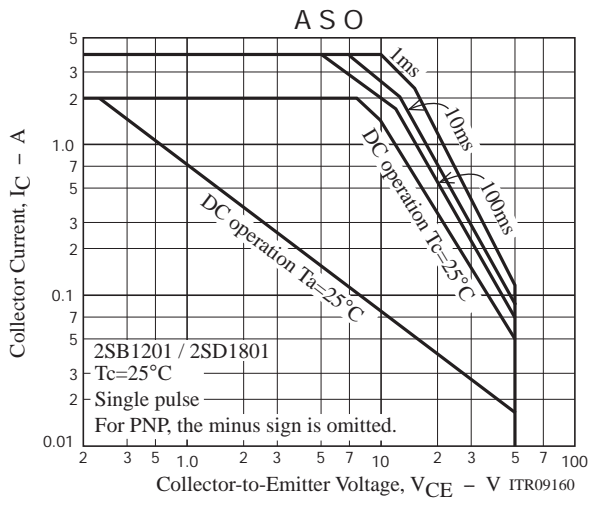
2SB1201/2SD1801



# 2SB1201/2SD1801



# 2SB1201/2SD1801



# 2SB1201/2SD1801

## Taping Specification

2SB1201S-TL-E, 2SB1201T-TL-E, 2SD1801S-TL-E, 2SD1801T-TL-E

### Packing Format

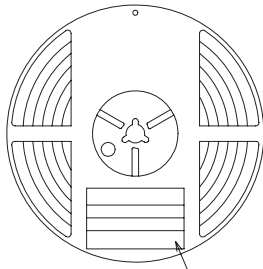
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
TP-FA	TP	700	2,100	12,600	3 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label  
(unit: mm)

Outer box label

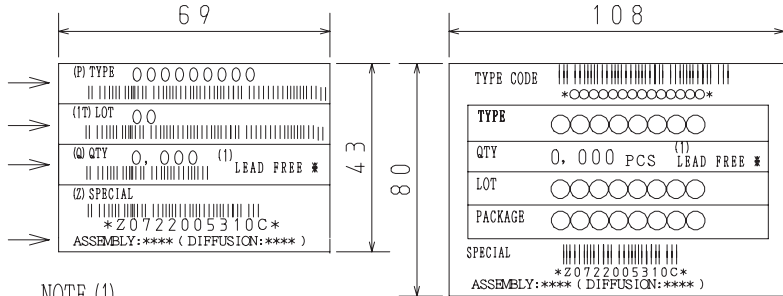
It is a label at the time of factory shipments.  
The form of a label may change in physical distribution process.

### Packing method



Type No.  
LOT No.  
Quantity  
Origin

Reel label



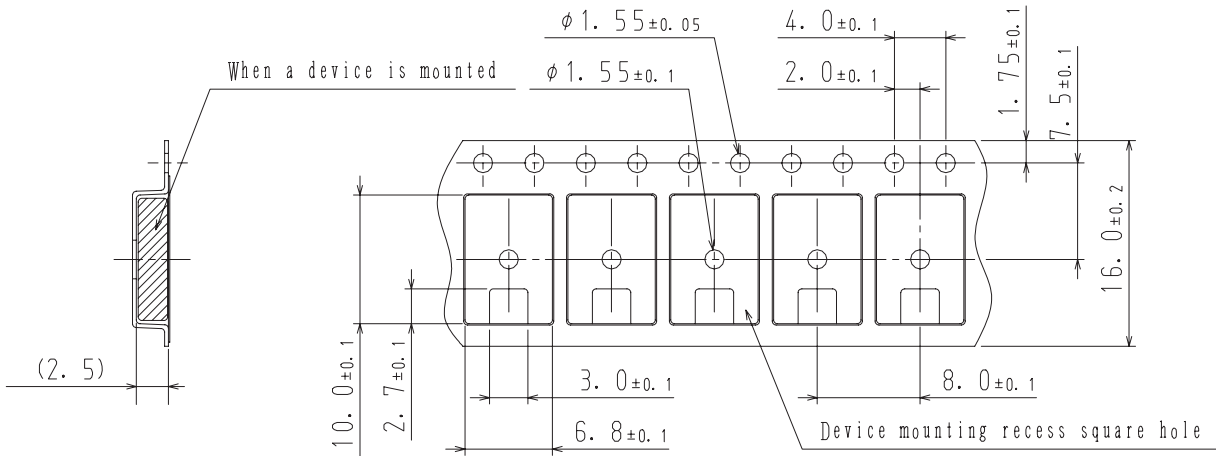
NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

### Taping configuration

1. Carrier tape size (unit:mm)



2. Device placement direction

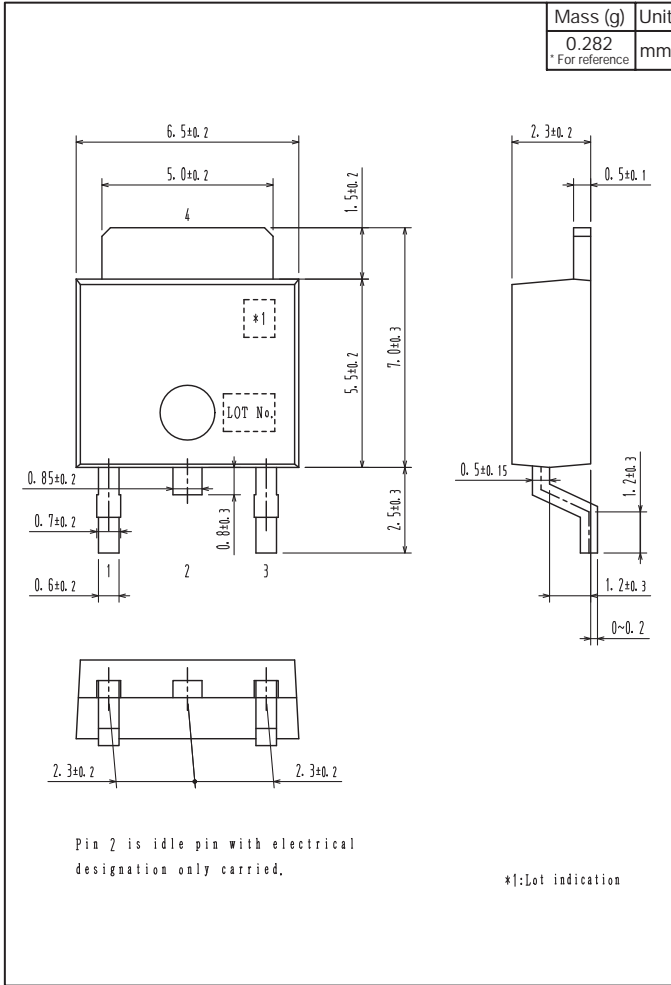


Those with one electrode terminal on the feed hole side.....TL

# 2SB1201/2SD1801

## Outline Drawing

2SB1201S-TL-E, 2SB1201T-TL-E, 2SD1801S-TL-E, 2SD1801T-TL-E



## Land Pattern Example



# 2SB1201/2SD1801

## Bag Packing Specification

2SB1201S-E, 2SB1201T-E, 2SD1801S-E, 2SD1801T-E

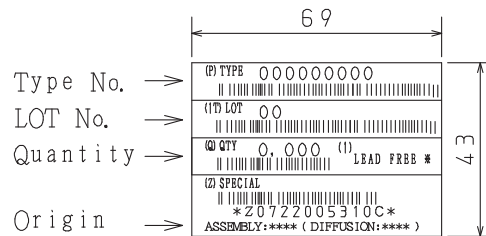
### 1. Packing Format

Package Name	Maximum Number of devices contained (pcs)			
	Bag	Inner box	Outer box	
TP	500	B-1	A-1	A-2
		10,000	50,000	30,000
	Packing format (Dimensions:mm (external))			
		Inner box	Outer box	
		B-1	A-1	A-2
		445×225×55	470×250×300	470×250×190

### 2. Bag dimensions (unit:mm)



### 3. Bag label, Inner box label (unit:mm)



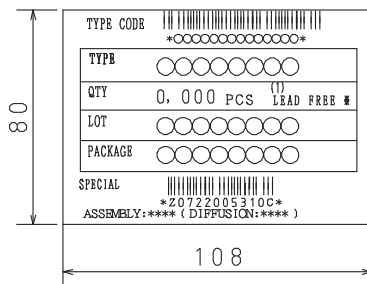
### 4. Outer box label (unit:mm)

It is a label at the time of factory shipments.  
The form of a label may change in physical distribution process.

#### NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

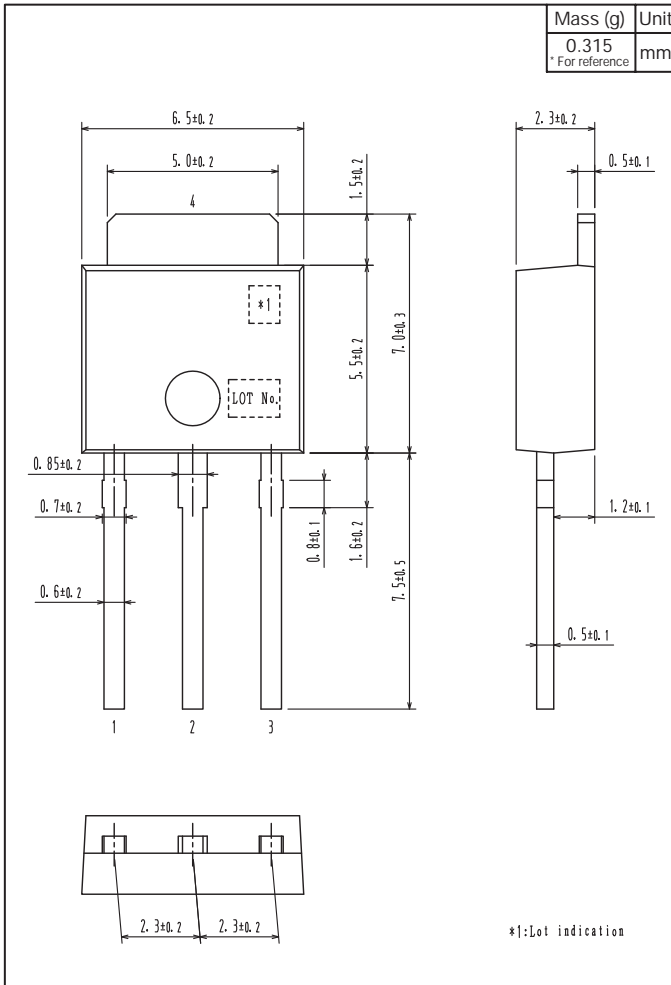




# 2SB1201/2SD1801

## Outline Drawing

2SB1201S-E, 2SB1201T-E, 2SD1801S-E, 2SD1801T-E



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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.